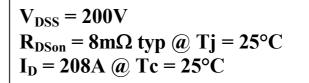
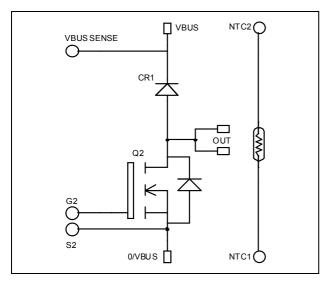


Boost chopper MOSFET Power Module





G2 🌡

S2 I

G2 #

OUT

NTC2 #

NTC1 #

O/VBUS

Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

Features

- Power MOS 7[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- Internal thermistor for temperature monitoring
- High level of integration



- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS compliant

Absolute maximum ratings

VBUS

VBUS

Symbol	Parameter	Max ratings	Unit	
$V_{ m DSS}$	Drain - Source Breakdown Voltage	200	V	
T	Continuous Drain Current	$T_c = 25^{\circ}C$	208	
I_{D}	Continuous Drain Current	$T_c = 80^{\circ}C$	155	A
I_{DM}	Pulsed Drain current	832		
V_{GS}	Gate - Source Voltage	±30	V	
R _{DSon}	Orain - Source ON Resistance		10	mΩ
P_{D}	Maximum Power Dissipation	ower Dissipation $T_c = 25^{\circ}C$		W
I_{AR}	Avalanche current (repetitive and non repetitive)		100	A
E_{AR}	Repetitive Avalanche Energy		50	mJ
E_{AS}	Single Pulse Avalanche Energy		3000	1113

These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 200V$ $T_j = 25^{\circ}C$			150	μА
		$V_{GS} = 0V, V_{DS} = 160V$ $T_j = 125^{\circ}C$			750	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 104A$		8	10	mΩ
V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5mA$	3		5	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$			±150	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		14.4		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		4.66		nF
C_{rss}	Reverse Transfer Capacitance	f=1MHz		0.29		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		280		
$Q_{\rm gs}$	Gate – Source Charge	$V_{Bus} = 100V$		106		nC
Q_{gd}	Gate – Drain Charge	$I_D = 208A$		134		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		32		ns
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$ $V_{GS} = 122V$		64		
$T_{d(off)}$	Turn-off Delay Time	$\begin{aligned} V_{Bus} &= 133V \\ I_D &= 208A \\ R_G &= 2.5\Omega \end{aligned}$		88		
T_{f}	Fall Time			116		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V$, $V_{Bus} = 133V$ $I_D = 208A$, $R_G = 2.5\Omega$		1698		T
E _{off}	Turn-off Switching Energy			1858		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C $V_{GS} = 15V, V_{Bus} = 133V$ $I_D = 208A, R_G = 2.5\Omega$		1872		т
E_{off}	Turn-off Switching Energy			1972		μJ

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit	
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			200			V	
I _{RM}	Maximum Reverse Leakage Current	V _R =200V	$T_j = 25$ °C			500	μΑ	
			$T_j = 125^{\circ}C$		100	750		
I_F	DC Forward Current		$T_c = 80^{\circ}C$		180		Α	
		$I_{\rm F} = 180A$			1.1	1.15		
$V_{\rm F}$	Diode Forward Voltage	$I_F = 360A$			1.4		V	
		$I_F = 180A$	$T_j = 125^{\circ}C$		0.9			
t _{rr}	Reverse Recovery Time	$I_F = 180A$ $T_j = 125$ °C	$T_j = 25$ °C		31		ns	
			$T_j = 125$ °C		60		115	
Q _{rr}	Reverse Recovery Charge	$V_R = 133V$ $di/dt = 600A/\mu s$	$T_j = 25$ °C		180		пС	
			$T_j = 125$ °C		750		iic	



Thermal and package characteristics

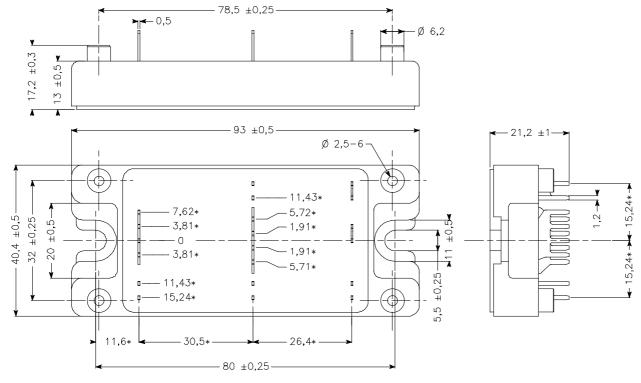
Symbol	Characteristic			Min	Typ	Max	Unit
R_{thJC}	Linction to Case Thermal Resistance		Transistor			0.16	°C/W
			Diode			0.32	C/ W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To Heatsink	M5	2.5		4.7	N.m
Wt	Package Weight				160	g	

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit	
R ₂₅	Resistance @ 25°C		50		kΩ	l
${ m B}_{25/85}$	$T_{25} = 298.15 \text{ K}$		3952		K	l

$$R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermistor temperature R_T: Thermistor value at T

SP4 Package outline (dimensions in mm)

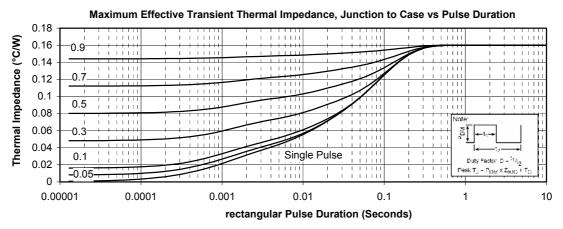


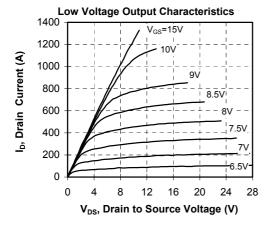
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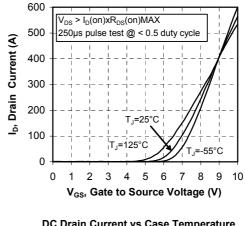
See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com



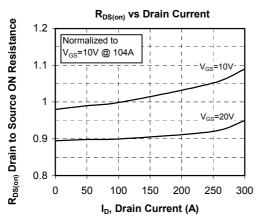
Typical Performance Curve

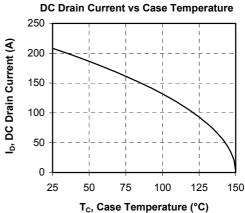




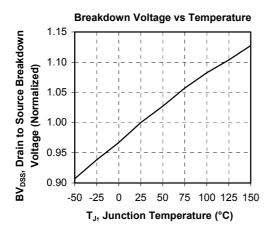


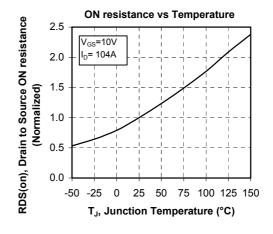
Transfert Characteristics

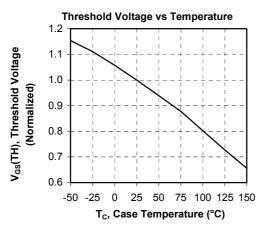


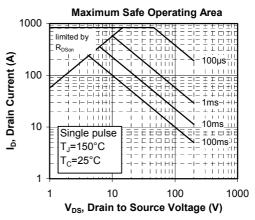


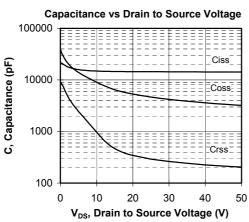


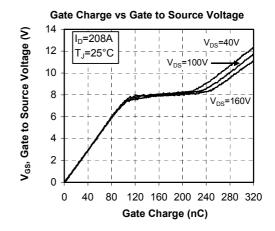






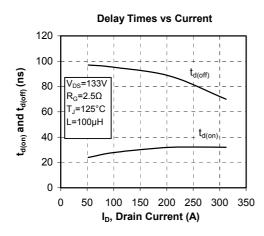


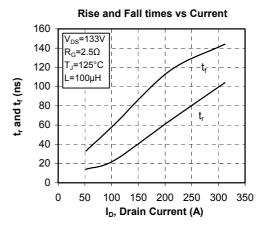


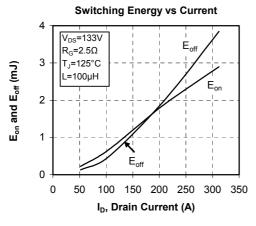


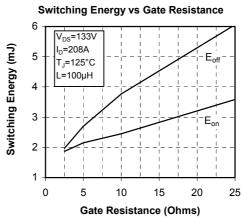
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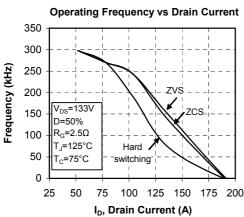


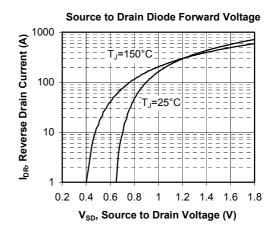












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